COMPLIANT GREEN

(5-2008)³



Vishay Semiconductors

Matched Pairs of Emitters and Detectors



DESCRIPTION

96 12317_1

The TCZT8020 include matched infrared emitters and phototransistors in leaded packages, used to assemble custom-designed transmissive sensors or reflective sensors. The phototransistor package blocks visible light.

FEATURES

- Package type: leaded
- · Detector type: phototransistor
- Dimensions (L x W x H in mm): 4.4 x 2 x 3
- Typical output current under test: I_C = 0.5 mA
- Daylight blocking filter
- Emitter wavelength: 950 nm
- Angle of half intensity: $\varphi = \pm 25^{\circ}$
- S420P: single detector component (dark epoxy)
- V420P: single emitter component (clear epoxy)
- Lead (Pb)-free soldering released
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

APPLICATIONS

- · Custom-design sensors for various distances
- · Reflective sensors
- Transmissive sensors

PRODUCT SUMMARY				
PART NUMBER	GAP WIDTH (mm)	TYPICAL OUTPUT CURRENT UNDER TEST ⁽¹⁾ (mA)	DAYLIGHT BLOCKING FILTER INTEGRATED	
TCZT8020	Variable	0.5	Yes	

Note

⁽¹⁾ Conditions like in table basic characteristics/coupler

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	VOLUME (1)	REMARKS		
TCZT8020	Bulk	MOQ: 2000 pairs, 1000 pcs/bulk	Detectors and emitters in separate bulk		

Note

(1) MOQ: minimum order quantity

^{**} Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
COUPLER				
Ambient temperature range		T _{amb}	- 55 to + 85	°C
Storage temperature range		T _{stg}	- 55 to + 100	°C
Soldering temperature	Distance to package 2 mm, t ≤ 5 s	T _{sd}	260	°C
INPUT (EMITTER)				
Reverse voltage		V _R	6	V
Forward current		l _F	60	mA
Forward surge current	t ≤ 10 μs	I _{FSM}	1	Α
Power dissipation	T _{amb} ≤ 25 °C	P _V	100	mW
Junction temperature		Tj	100	°C
OUTPUT (DETECTOR)			<u>. </u>	
Collector emitter voltage		V _{CEO}	70	V
Emitter collector voltage		V _{ECO}	7	V
OUTPUT (DETECTOR)				
Collector current		I _C	50	mA
Collector peak current	$t_p/T = 0.5, t \le 10 \text{ ms}$	I _{CM}	100	mA
Power dissipation	T _{amb} ≤ 25 °C	P _V	150	mW
Junction temperature		T _j	100	°C

ABSOLUTE MAXIMUM RATINGS

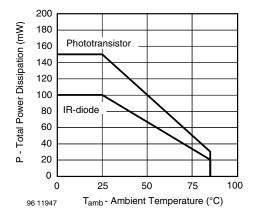


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature



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BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
COUPLER	•					
Collector current	$V_{CE} = 5 \text{ V}, I_F = 20 \text{ mA}, d = 4 \text{ mm}^{(1)}$	I _C	0.25	0.5		mA
I _C /I _F	$V_{CE} = 5 \text{ V}, I_F = 20 \text{ mA}, d = 4 \text{ mm}$	CTR	1.25	2.5		%
Collector emitter saturation voltage	$I_F = 20 \text{ mA}, I_C = 25 \mu\text{A}$	V _{CEsat}			0.4	V
Cut-off frequency	I_F = 10 mA, V_{CE} = 5 V, R_L = 100 Ω	f _C		110		kHz
INPUT (EMITTER)	•					
Forward voltage	I _F = 50 mA	V _F		1.25	1.6	V
Radiant intensity	$I_F = 60 \text{ mA}, t_P = 20 \text{ ms}$	l _e			7.8	mW/sr
Peak wavelength	I _F = 100 mA	λ _P	940			nm
Virtual source diameter	DIN EN ISO 1146/1:2005	d		1.1		mm
OUTPUT (DETECTOR)						
Collector emitter voltage	I _C = 1 mA	V _{CEO}	70			V
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V
Collector dark current	$V_{CE} = 25 \text{ V}, I_F = 0 \text{ A}, E = 0 \text{ Ix}$	I _{CEO}			100	nA
SWITCHING CHARACTERISTI	cs					
Turn-on time	$V_S = 5 \text{ V}, I_C = 1 \text{ mA}, R_L = 100 \Omega$ (see figure 10)	t _{on}		15		μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 1 \text{ mA}, R_L = 100 \Omega$ (see figure 10)	t _{off}		10		μs

Note

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

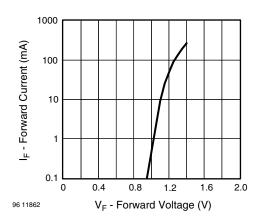


Fig. 2 - Forward Current vs. Forward Voltage

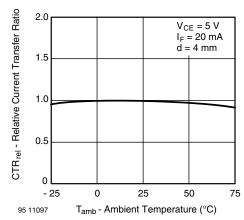


Fig. 3 - Relative Current Transfer Ratio vs. Ambient Temperature

⁽¹⁾ Characteristics are measurement with d = 4 mm (0.55") distance between emitter and detector, within a common axis of 0.5 mm (0.02") and with parallel alignment within 5°

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Matched Pairs of Emitters and **Detectors**



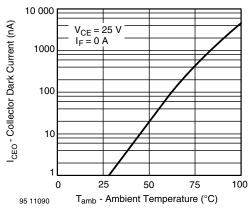


Fig. 4 - Collector Dark Current vs. Ambient Temperature

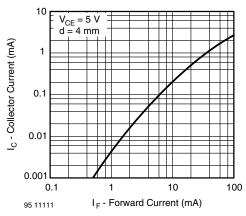


Fig. 5 - Collector Current vs. Forward Current

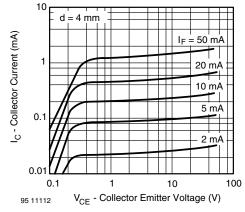


Fig. 6 - Collector Current vs. Collector Emitter Voltage

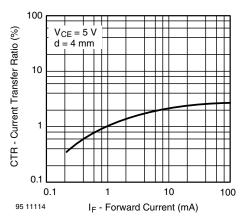


Fig. 7 - Current Transfer Ratio vs. Forward Current

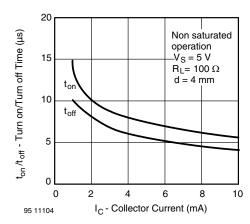


Fig. 8 - Turn on/off Time vs. Forward Current

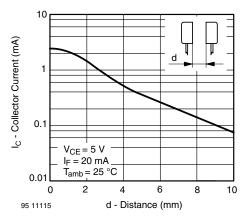


Fig. 9 - Collector Current vs. Distance



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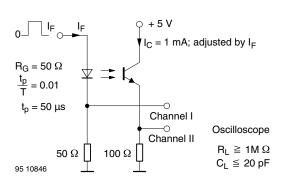


Fig. 10 - Pulse Diagram

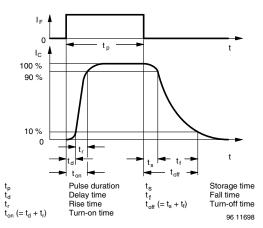
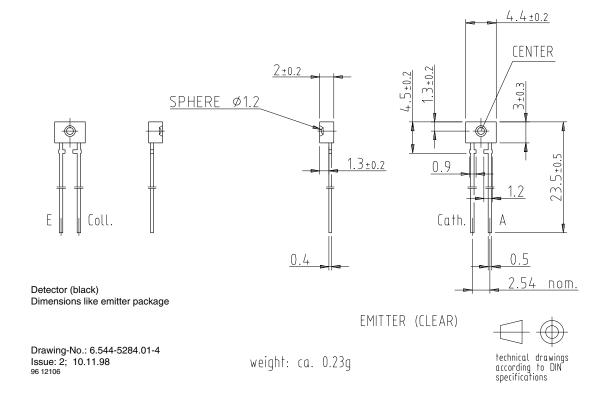


Fig. 11 - Switching Times

PACKAGE DIMENSIONS in millimeters



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Document Number: 91000 www.vishay.com
Revision: 11-Mar-11 1